SHINDENGEN

Schottky Rectifiers (SBD)

Dual

SF10SC3L

30V 10A

FEATURES

- Tj150℃
- Low V_F=0.45V
- P_{RRSM} avalanche guaranteed
- Fully Isolated Molding
- Dielectric strength 2kV guaranteed

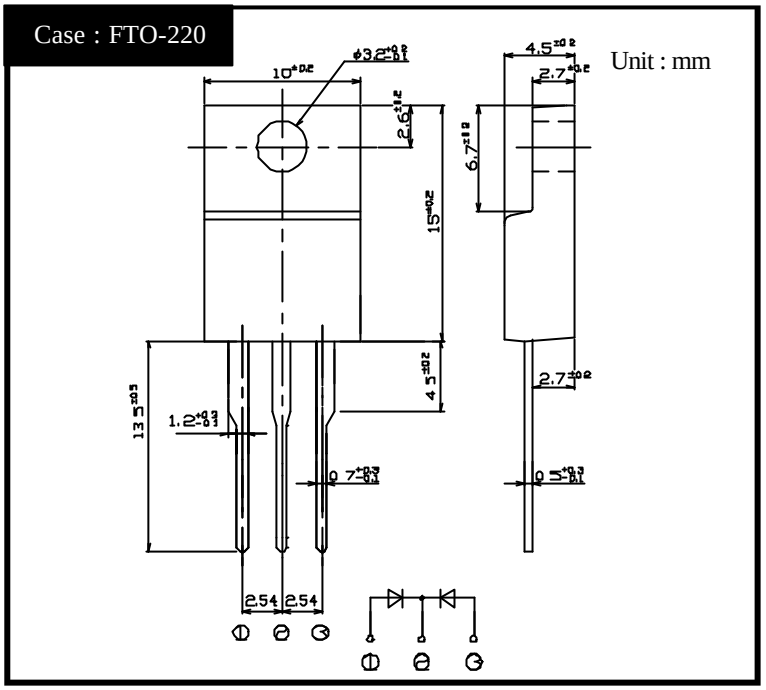
APPLICATION

- Switching power supply
- DC/DC converter
- Home Appliances, Office Equipment
- Telecommunication

OUTLINE DIMENSIONS

Case : FTO-220

Unit : mm



RATINGS

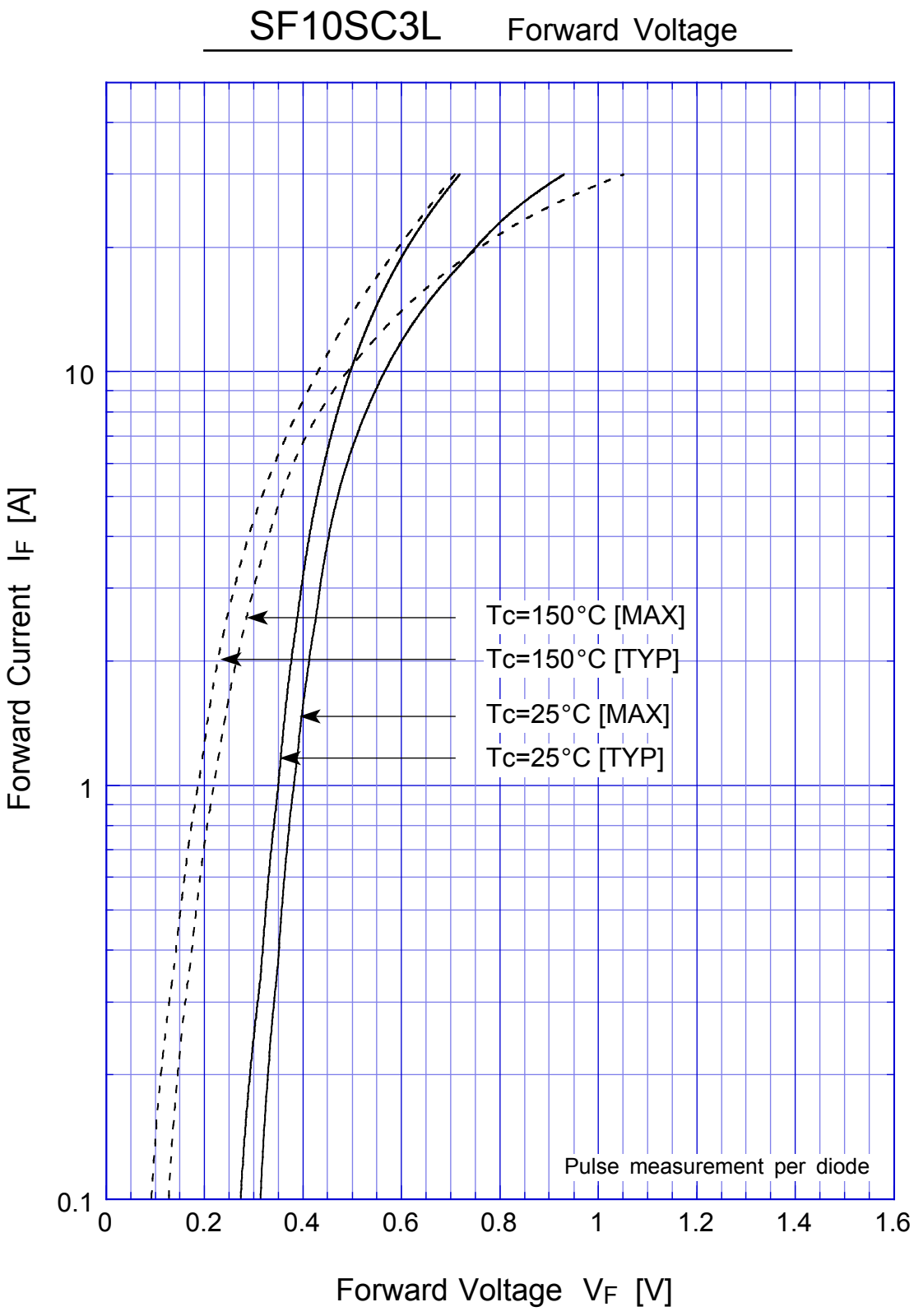
●Absolute Maximum Ratings (If not specified Tc=25℃)

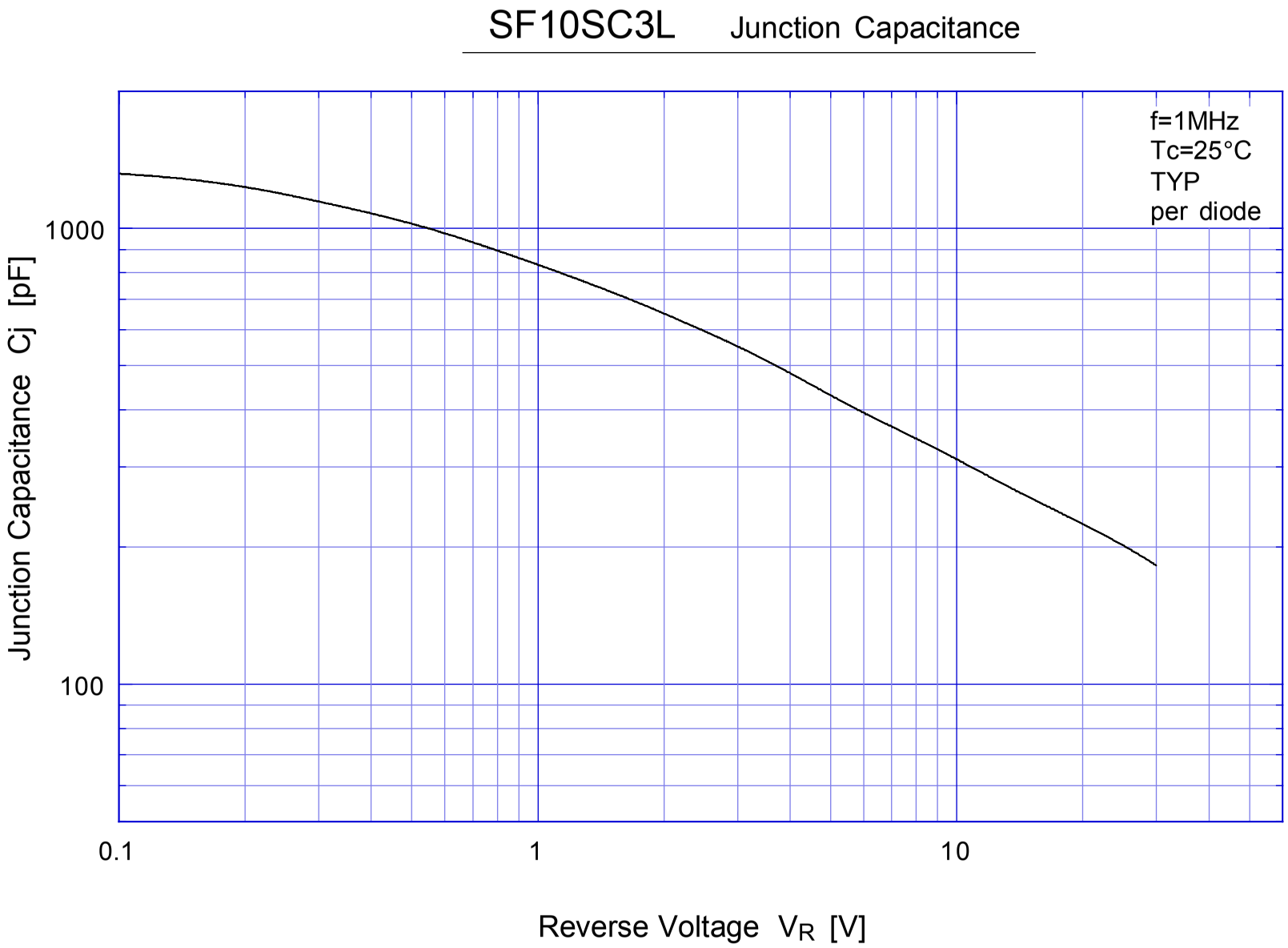
Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	Tstg		-55～150	℃
Operating Junction Temperature	Tj		150	℃
Maximum Reverse Voltage	V_{RM}		30	V
Repetitive Peak Surge Reverse Voltage	V_{RRSM}	Pulse width 0.5ms, duty 1/40	35	V
Average Rectified Forward Current	I_O	50Hz sine wave, R-load, Rating for each diode Io/2, Tc=139℃	10	A
Peak Surge Forward Current	I_{FSM}	50Hz sine wave, Non-repetitive 1 cycle peak value, Tj=25℃	150	A
Repetitive Peak Surge Reverse Power	P_{RRSM}	Pulse width 10μs, Rating of per diode, Tj=25℃	330	W
Dielectric Strength	Vdis	Terminals to case, AC 1 minute	2	kV
Mounting Torque	TOR	(Recommended torque :0.3N･m)	0.5	N･m

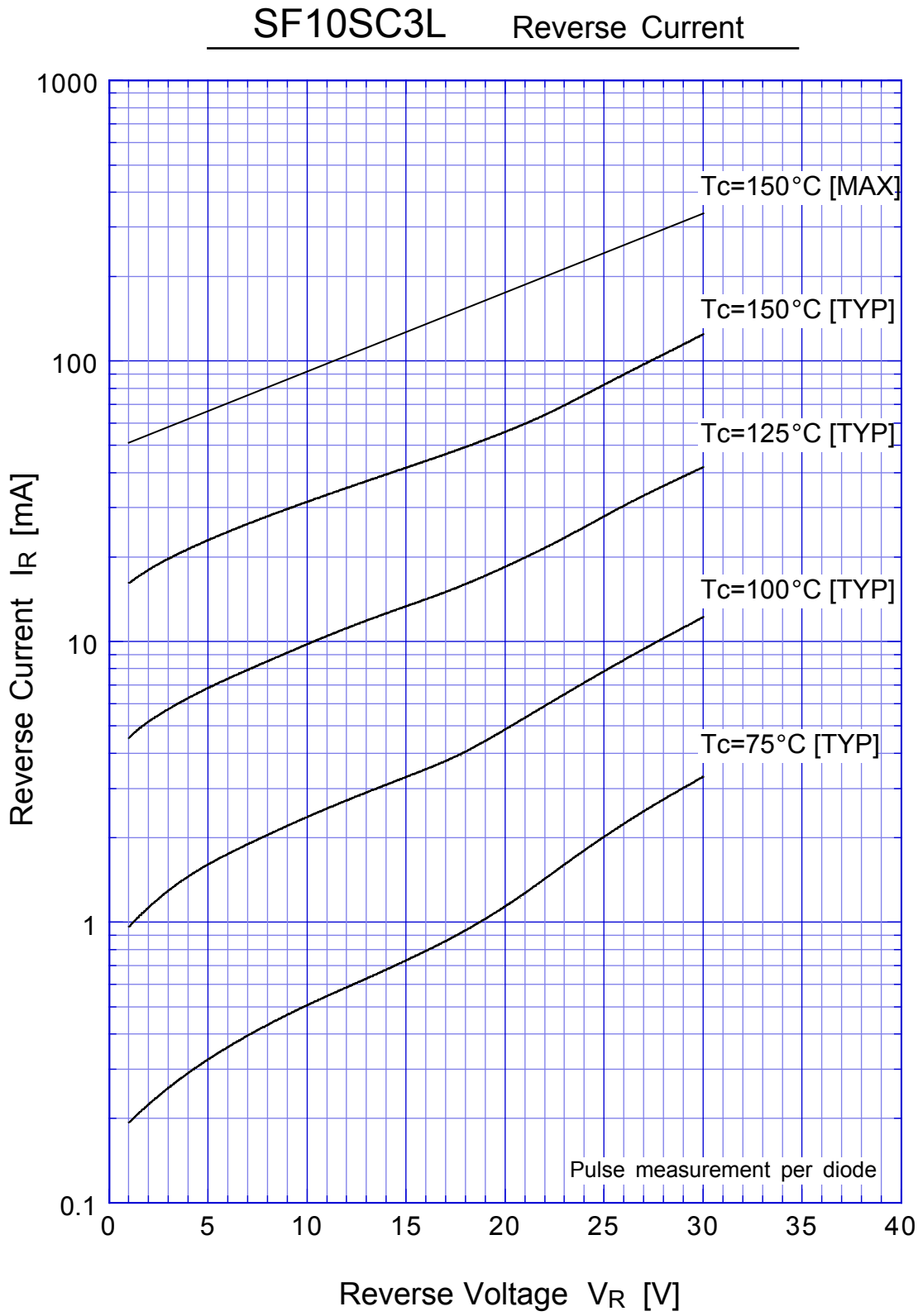
●Electrical Characteristics (If not specified Tc=25℃)

Item	Symbol	Conditions	Ratings	Unit
Forward Voltage	V_F	I_F=4A, Pulse measurement, Rating of per diode	Max.0.45	V
Reverse Current	I_R	V_R=V_{RM}, Pulse measurement, Rating of per diode	Max.5	mA
Junction Capacitance	Cj	f=1MHz, V_R=10V, Rating of per diode	Typ.310	pF
Thermal Resistance	θjc	junction to case	Max.2.3	℃/W

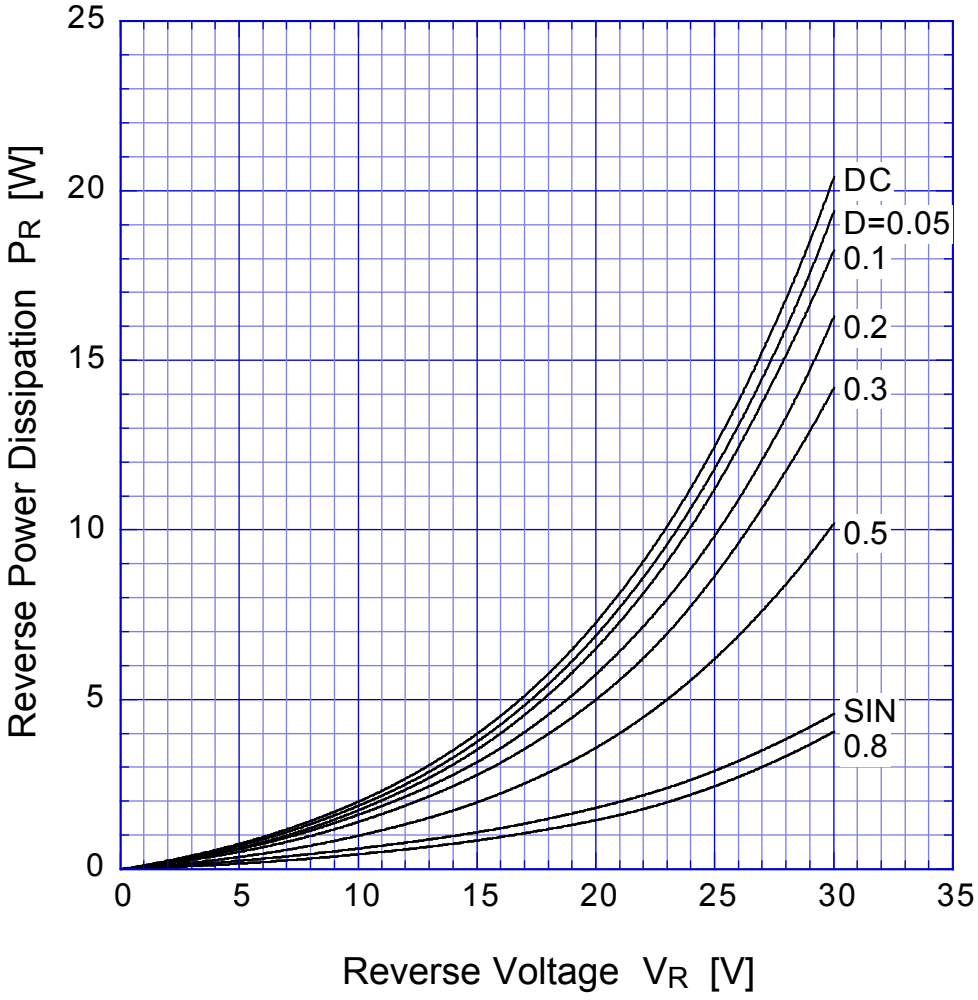
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SF10SC3L Forward Voltage
Forward Current IF [A]
10
1
0.1
0
0.2
0.4
0.6
0.8
1
1.2
1.4
1.6
Forward Voltage VF [V]
Tc=150°C [MAX]
Tc=150°C [TYP]
Tc=25°C [MAX]
Tc=25°C [TYP]
Pulse measurement per diode

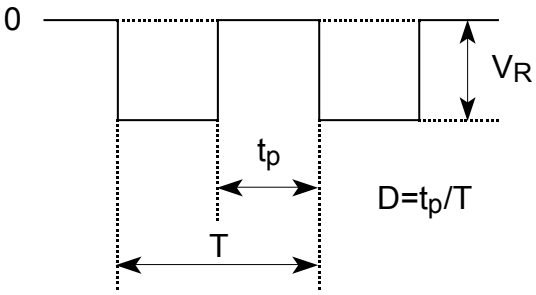

SF10SC3L Junction Capacitance
f=1MHz
Tc=25°C
TYP
per diode
1000
100
Junction Capacitance Cj [pF]
0.1
1
10
Reverse Voltage VR [V]


SF10SC3L Reverse Current
1000
100
10
1
0.1
Reverse Current IR [mA]
Tc=150°C [MAX]
Tc=150°C [TYP]
Tc=125°C [TYP]
Tc=100°C [TYP]
Tc=75°C [TYP]
Pulse measurement per diode
0
5
10
15
20
25
30
35
40
Reverse Voltage VR [V]

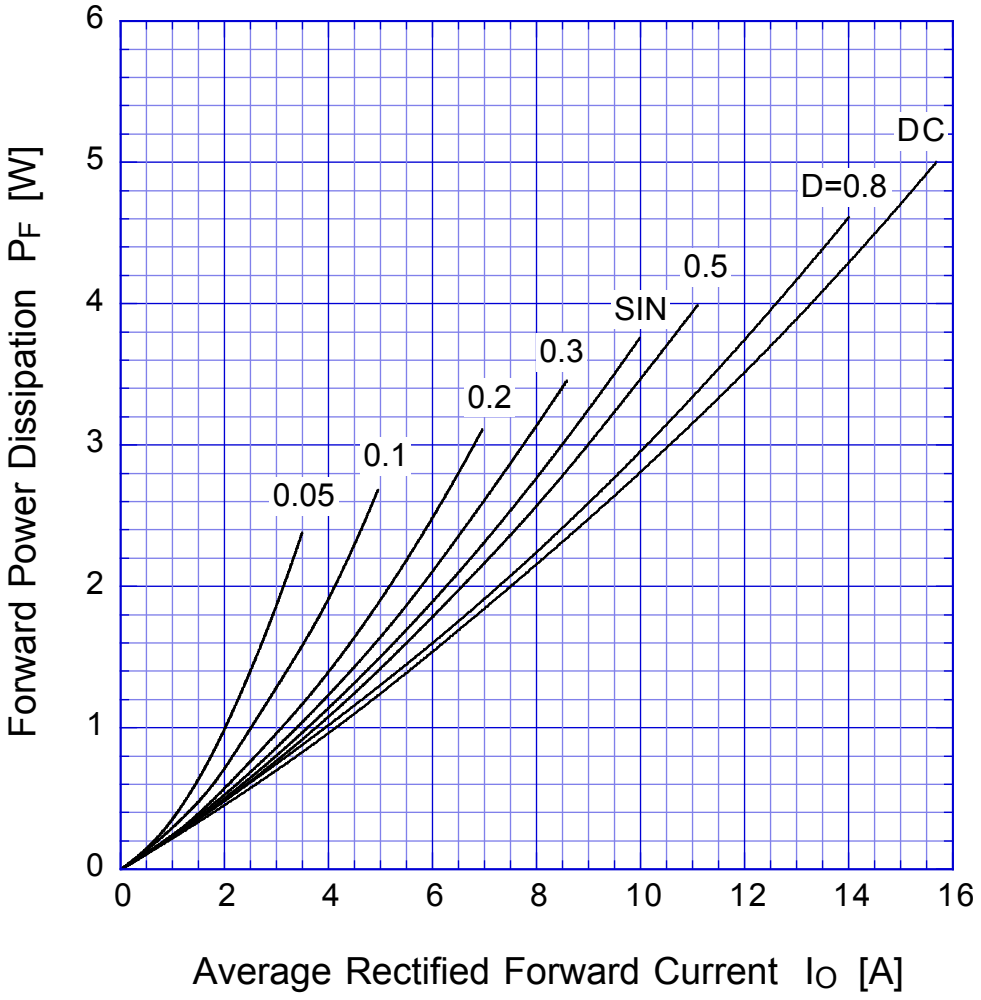
SF10SC3L Reverse Power Dissipation



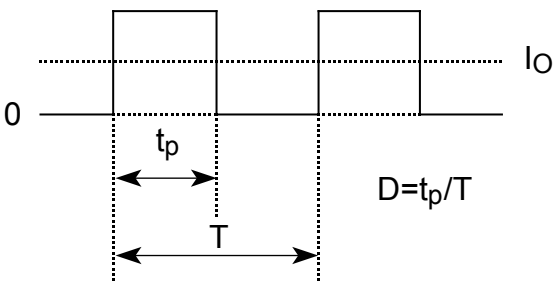
Tj = 150°C



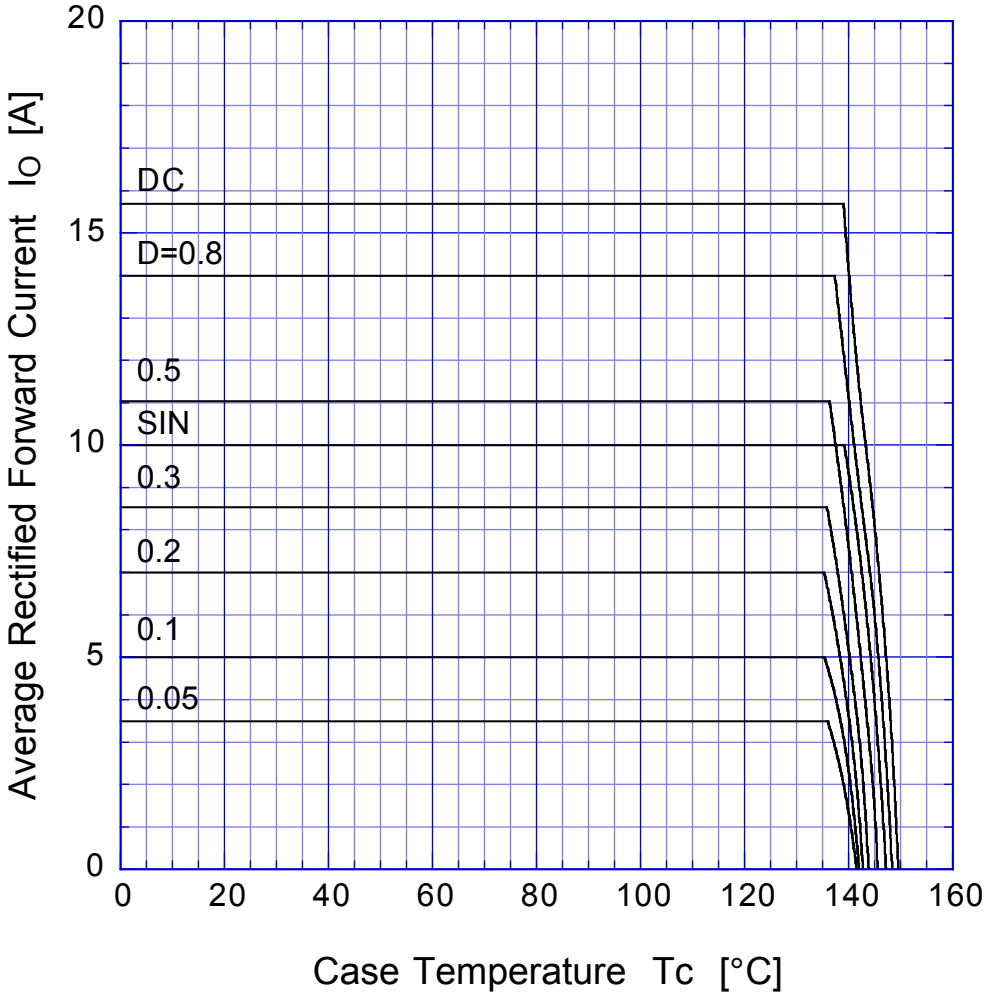
SF10SC3L Forward Power Dissipation



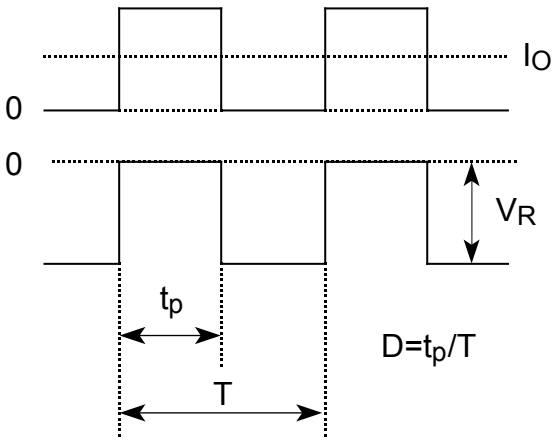
Tj = 150°C



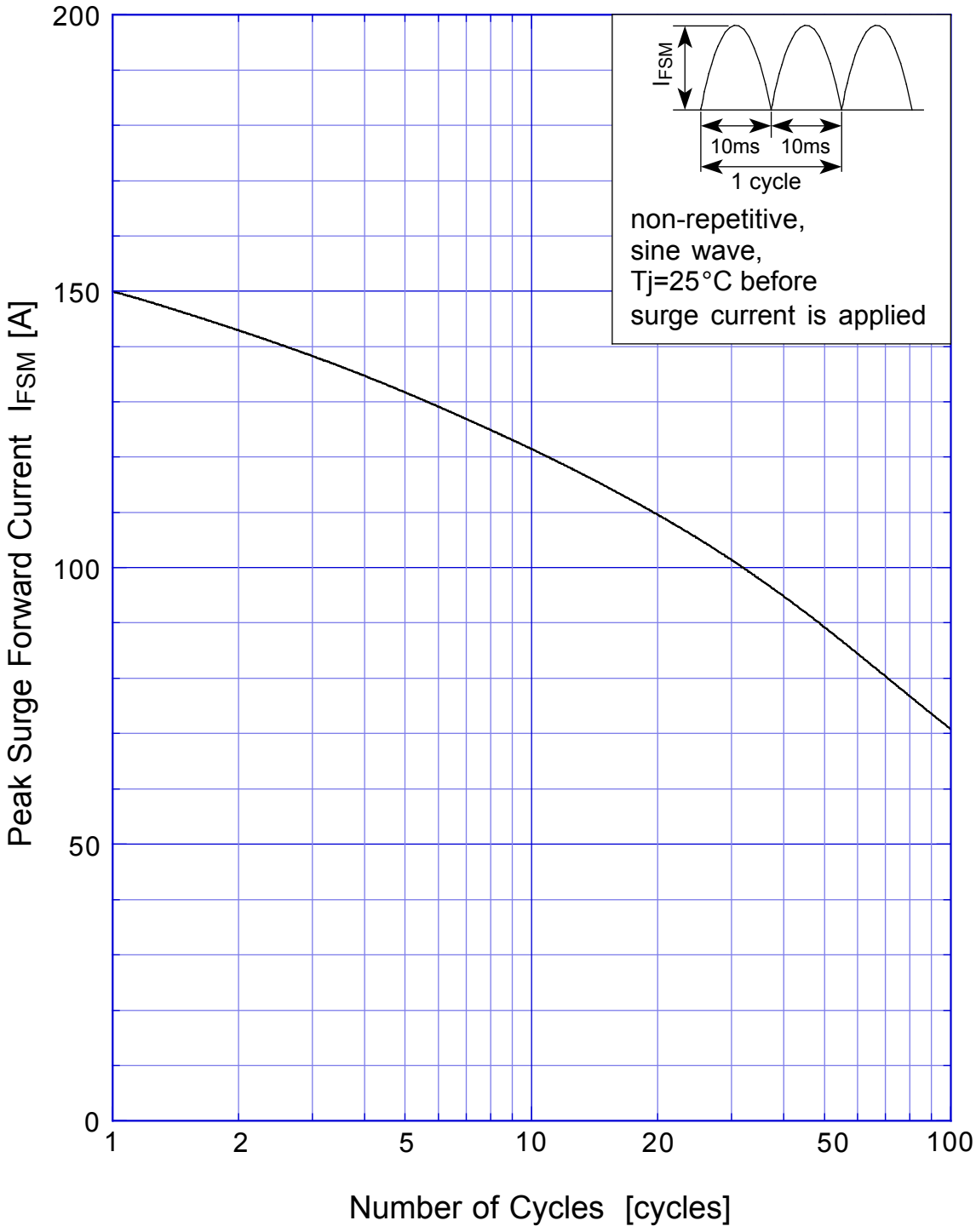
SF10SC3L Derating Curve



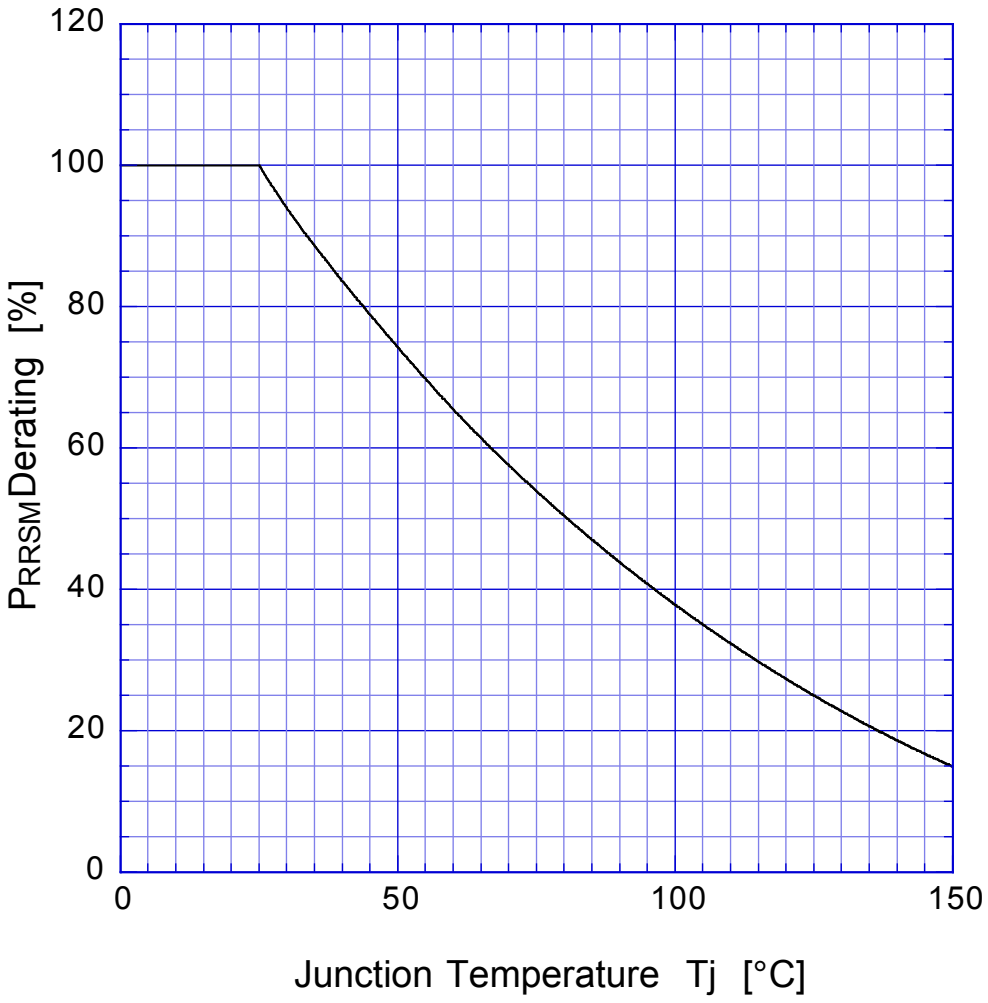
V_R = 30V

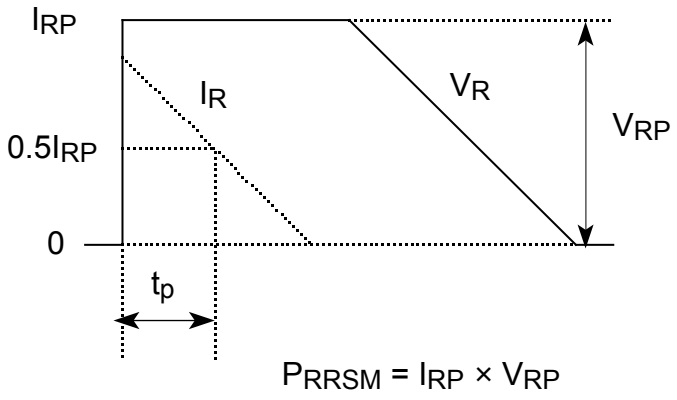


SF10SC3L Peak Surge Forward Capability



SBD Repetitive Surge Reverse Power Derating Curve





SBD Repetitive Surge Reverse Power Capability

